NSN 5962-01-238-6198

Memory Microcircuit - Page 1 of 2



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Body Length:	
0.925 inches	
Body Width:	
0.520 inches	
Body Height:	
0.172 inches	
Maximum Power Dissipation Rating:	
570.0 milliwatts	
Operating Tempurature Range:	
-55.0/+125.0 degrees celsius	
Storage Tempurature Range:	
-65.0/+150.0 degrees celsius	
End Application:	
Display assembl 84-27401-001	
Features Provided:	
Electrostatic sensitive and hermetically sealed and burn in and fast settling and w/resistor	
Inclosure Material:	
Ceramic	
Inclosure Configuration:	
Dual-in-line	
Output Logic Form:	
Transistor-transistor logic	
Input Circuit Pattern:	
9 input	
Criticality Code Justification:	
Feat	
Terminal Surface Treatment:	
Gold	
Voltage Rating And Type Per Characteristic:	
7.0 volts power source	
Time Rating Per Chacteristic:	
2500.00 nanoseconds propagation delay time, low to high level output and 2500.00 nanoseconds propagation delay time, high to low level	
output	
Memory Device Type:	
Ram	
Memory Capacity:	
Unknown	
Special Features:	
Nuclear hardness critical item	
Test Data Document:	
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).	
Terminal Type And Quantity:	
18 printed circuit	

18 printed circuit

NSN 5962-01-238-6198

Memory Microcircuit - Page 2 of 2

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

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